

BAS32L

High-speed switching diode

Rev. 06 — 29 October 2008

Product data sheet

1. Product profile

1.1 General description

Single high-speed switching diode, fabricated in planar technology, and encapsulated in a small hermetically sealed glass SOD80C Surface-Mounted Device (SMD) package.

1.2 Features

- High switching speed: $t_{rr} \leq 4 \text{ ns}$
- Reverse voltage: $V_R \leq 75 \text{ V}$
- Repetitive peak reverse voltage: $V_{RRM} \leq 100 \text{ V}$
- Repetitive peak forward current: $I_{FRM} \leq 450 \text{ mA}$
- Small hermetically sealed glass SMD package

1.3 Applications

- High-speed switching
- Reverse polarity protection

1.4 Quick reference data

Table 1. Quick reference data

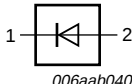
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_F	forward current	[1]	-	-	200	mA
I_{FRM}	repetitive peak forward current		-	-	450	mA
V_R	reverse voltage		-	-	75	V
V_F	forward voltage	$I_F = 100 \text{ mA}$	-	-	1000	mV
t_{rr}	reverse recovery time	[2]	-	-	4	ns

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] When switched from $I_F = 10 \text{ mA}$ to $I_R = 10 \text{ mA}$; $R_L = 100 \Omega$; measured at $I_R = 1 \text{ mA}$.

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode		
2	anode		

[1] The marking band indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BAS32L	-	hermetically sealed glass surface-mounted package; 2 connectors	SOD80C

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
BAS32L	marking band

[1] black: made in Philippines
brown: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_R	reverse voltage		-	75	V
I_F	forward current		[1] -	200	mA
I_{FRM}	repetitive peak forward current		-	450	mA
I_{FSM}	non-repetitive peak forward current	square wave	[2]		
		$t_p = 1 \mu s$	-	4	A
		$t_p = 1 ms$	-	1	A
		$t_p = 1 s$	-	0.5	A
P_{tot}	total power dissipation	$T_{amb} = 25 \text{ }^\circ\text{C}$	[1] -	500	mW

Table 5. Limiting values ...continued*In accordance with the Absolute Maximum Rating System (IEC 60134).*

Symbol	Parameter	Conditions	Min	Max	Unit
T_j	junction temperature		-	200	°C
T_{amb}	ambient temperature		-65	+200	°C
T_{stg}	storage temperature		-65	+200	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] $T_j = 25\text{ °C}$ prior to surge.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	350	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	300	K/W

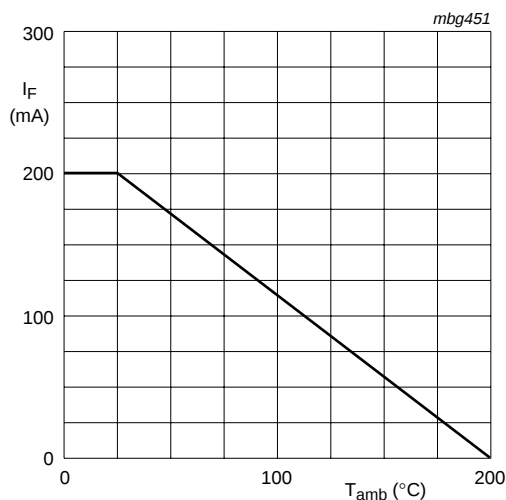
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7. Characteristics *$T_{amb} = 25\text{ °C}$ unless otherwise specified.*

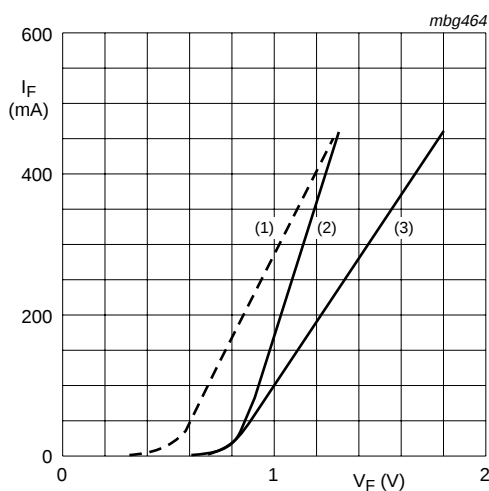
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_F	forward voltage	$I_F = 5\text{ mA}$	620	-	750	mV
		$I_F = 100\text{ mA}$	-	-	1000	mV
		$I_F = 100\text{ mA}; T_j = 100\text{ °C}$	-	-	930	mV
I_R	reverse current	$V_R = 20\text{ V}$	-	-	25	nA
		$V_R = 75\text{ V}$	-	-	5	μA
		$V_R = 20\text{ V}; T_j = 150\text{ °C}$	-	-	50	μA
		$V_R = 75\text{ V}; T_j = 150\text{ °C}$	-	-	100	μA
C_d	diode capacitance	$V_R = 0\text{ V}; f = 1\text{ MHz}$	-	-	2	pF
t_{rr}	reverse recovery time		[1]	-	4	ns
V_{FR}	forward recovery voltage		[2]	-	2.5	V

[1] When switched from $I_F = 10\text{ mA}$ to $I_R = 10\text{ mA}$; $R_L = 100\text{ Ω}$; measured at $I_R = 1\text{ mA}$.[2] When switched from $I_F = 50\text{ mA}$; $t_r = 20\text{ ns}$.



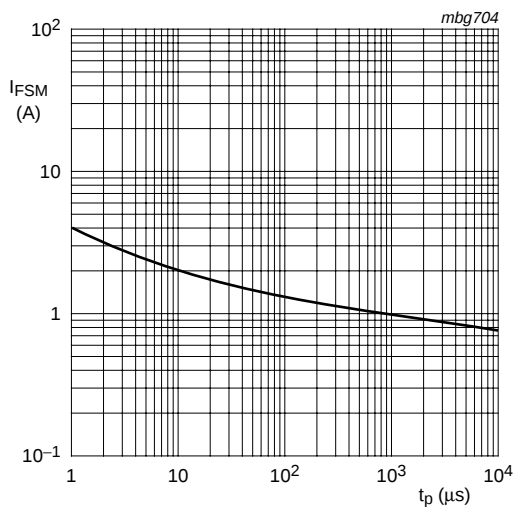
FR4 PCB, standard footprint

Fig 1. Forward current as a function of ambient temperature; derating curve



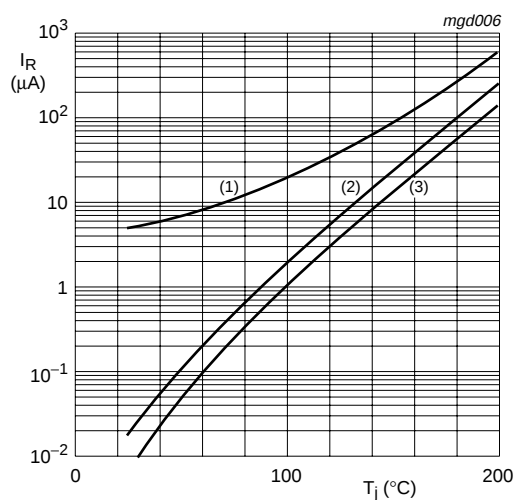
- (1) $T_J = 175\text{ °C}$; typical values
- (2) $T_J = 25\text{ °C}$; typical values
- (3) $T_J = 25\text{ °C}$; maximum values

Fig 2. Forward current as a function of forward voltage



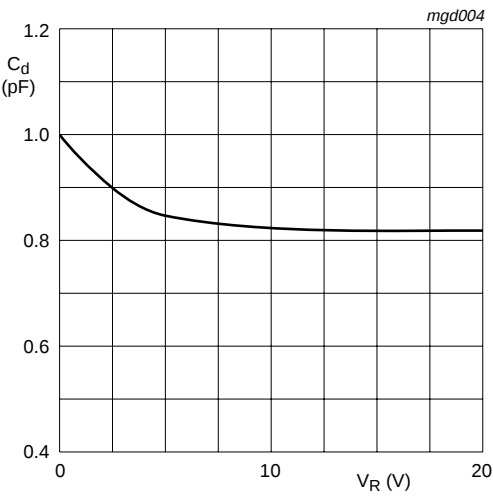
Based on square wave currents.
 $T_J = 25\text{ °C}$ prior to surge

Fig 3. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1) $V_R = 75\text{ V}$; maximum values
- (2) $V_R = 75\text{ V}$; typical values
- (3) $V_R = 20\text{ V}$; typical values

Fig 4. Reverse current as a function of junction temperature



f = 1 MHz; Tj = 25 °C

Fig 5. Diode capacitance as a function of reverse voltage; typical values

8. Test information

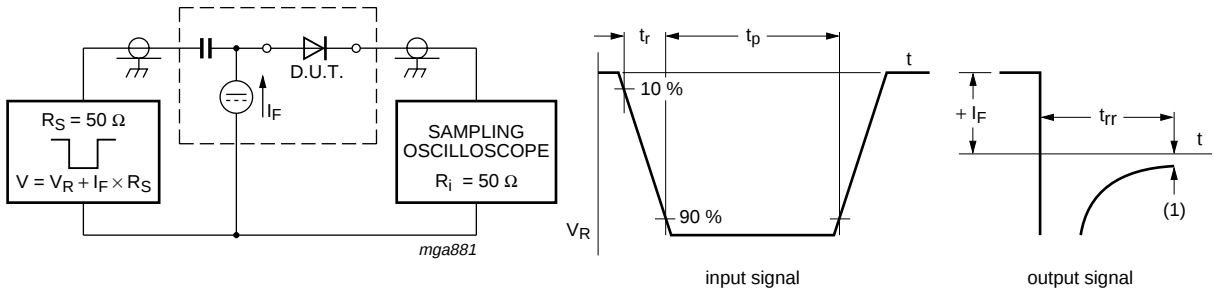


Fig 6. Reverse recovery time test circuit and waveforms

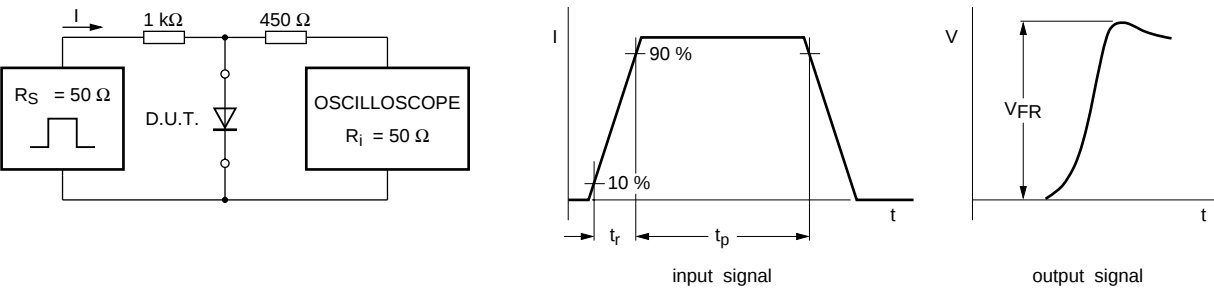
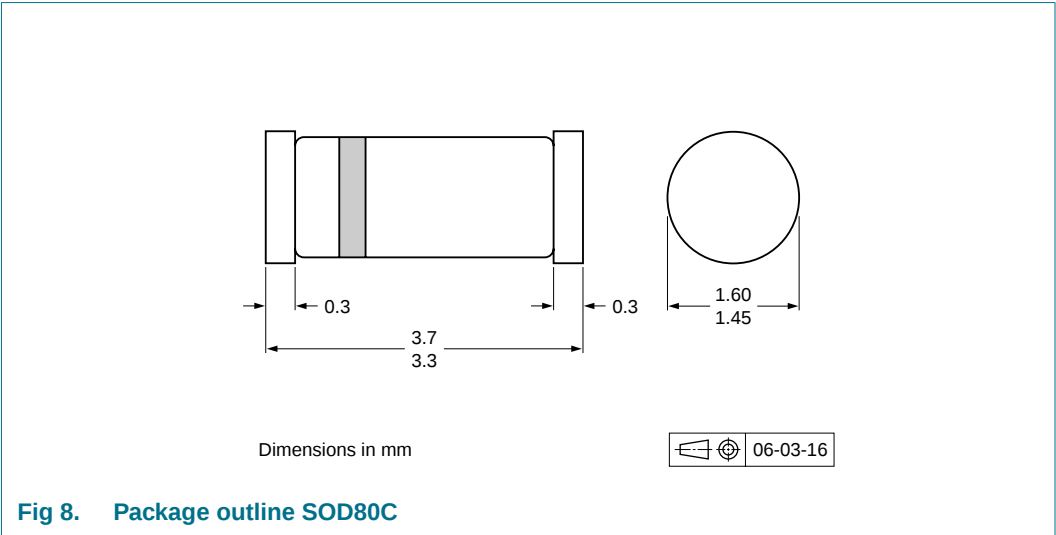


Fig 7. Forward recovery voltage test circuit and waveforms

9. Package outline



10. Packing information

Table 8. Packing methods				
The indicated -xxx are the last three digits of the 12NC ordering code. ^[1]				
Type number	Package	Description	Packing quantity	
			2500	10000
BAS32L	SOD80C	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering

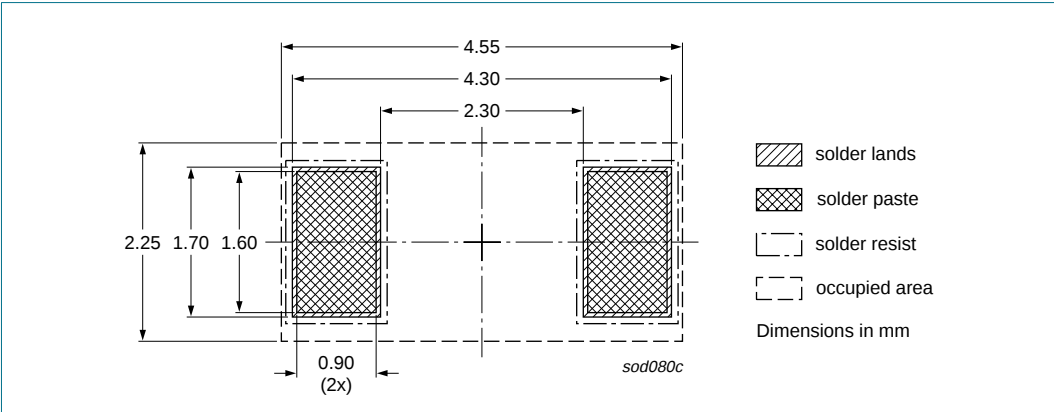


Fig 9. Reflow soldering footprint SOD80C

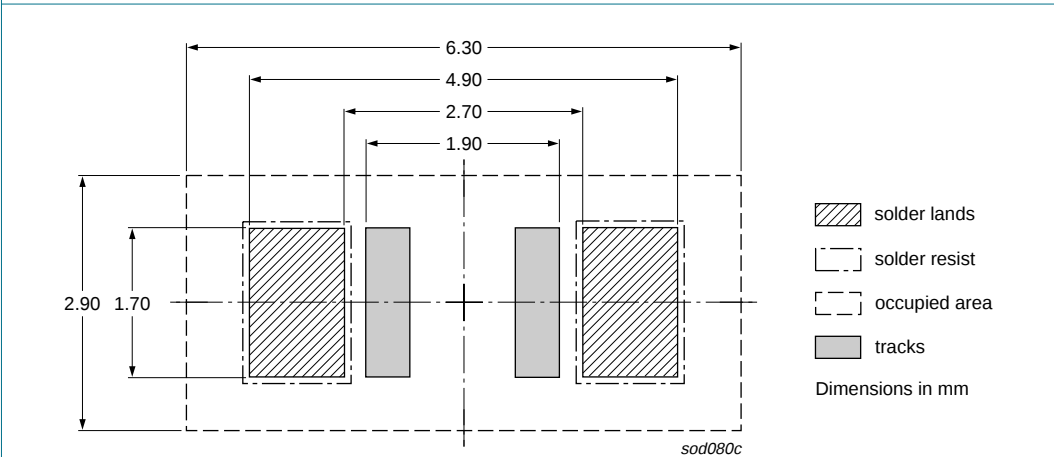


Fig 10. Wave soldering footprint SOD80C

12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS32L_6	20081029	Product data sheet	-	BAS32L_5
Modifications:	• Figure 8: amended • Section 13 "Legal information": updated			
BAS32L_5	20080103	Product data sheet	-	BAS32L_4
BAS32L_4	20050322	Product data sheet	-	BAS32L_3
BAS32L_3	20020123	Product specification	-	BAS32L_2
BAS32L_2	19960910	Product specification	-	BAS32L_1
BAS32L_1	19960423	Product specification	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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